

SBT5401

PNP Silicon Transistor

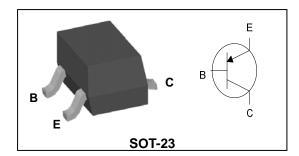
Description

- General purpose amplifier
- High voltage application

Features

- High collector breakdown voltage : $V_{CBO} = -160V$, $V_{CEO} = -160V$
- Low collector saturation voltage : $V_{CE(sat)} = -0.5V(MAX.)$
- Complementary pair with SBT5551

PIN Connection



Ordering Information

Type NO.	Marking	Package Code
SBT5401	<u>NFN</u> <u>□</u> ① ②	SOT-23

①Device Code ② Year&Week Code

Absolute maximum ratings

(Ta=25°C)

Characteristic	Symbol	Ratings	Unit
Collector-Base voltage	V_{CBO}	-160	V
Collector-Emitter voltage	$V_{\sf CEO}$	-160	V
Emitter-Base voltage	V_{EBO}	-5	V
Collector current	I _C	-600	mA
Collector dissipation	P _C	200	mW
Junction temperature	Tj	150	°C
Storage temperature	T_{stg}	-55~150	°C

Electrical Characteristics

(Ta=25°C)

Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Collector-Base breakdown voltage	BV _{CBO}	I _C =-100μA, I _E =0	-160	i	-	V
Collector-Emitter breakdown voltage	BV_CEO	I _C =-1mA, I _B =0	-160	-	-	V
Emitter-Base breakdown voltage	BV_{EBO}	I _E =-10μA, I _C =0	-5	-	-	V
Collector cut-off current	I _{CBO}	V _{CB} =-120V, I _E =0	-	-	-100	nA
Emitter cut-off current	I _{EBO}	$V_{EB} = -3V$, $I_{C} = 0$	_	-	-100	nA
DC current gain	h _{FE (1)}	V _{CE} =-5V, I _C =-1mA	50	-		-
DC current gain	h _{FE (2)}	V _{CE} =-5V, I _C =-10mA	60	-	240	-
DC current gain	h _{FE (3)}	$V_{CE} = -5V, I_{C} = -50mA$	50	-		-
Collector-Emitter saturation voltage	V _{CE(sat)(1)} *	I _C =-10mA, I _B =-1mA	_	-	-0.2	V
Collector-Emitter saturation voltage	V _{CE(sat)(2)} *	I _C =-50mA, I _B =-5mA	_	-	-0.5	V
Base-Emitter saturation voltage	V _{BE(sat)(1)} *	I _C =-10mA, I _B =-1mA	-	-	-1	V
Base-Emitter saturation voltage	V _{BE(sat)(2)*}	I _C =-50mA, I _B =-5mA	_	-	-1	V
Transition frequency	f _T	V _{CE} =-10V, I _C =-10mA	100	-	400	MHz
Collector output capacitance	C _{ob}	V _{CB} =-10V, I _E =0, f=1MHz	-	-	6	pF

^{* :} Pulse Tester : Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%

Electrical Characteristic Curves

Fig. 1 h_{FE} - I_{C}

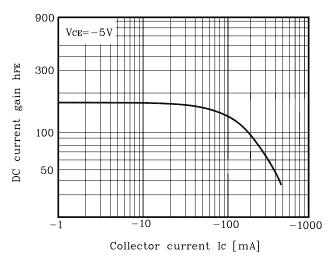


Fig. 3 f_T - I_C

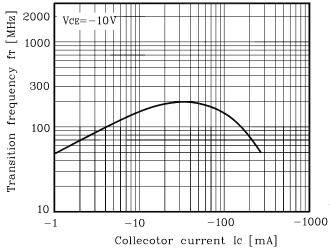


Fig. 5 C_{ob} - V_{CB}



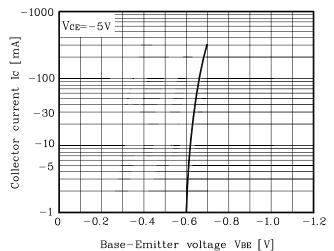
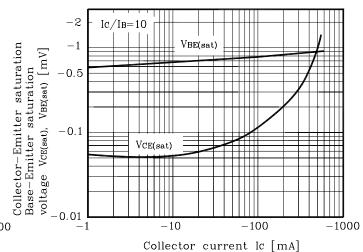


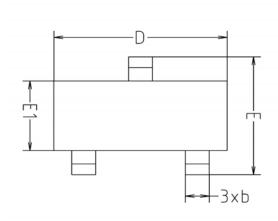
Fig. 4 $V_{CE(sat)}$, $V_{BE(sat)}$ - I_C

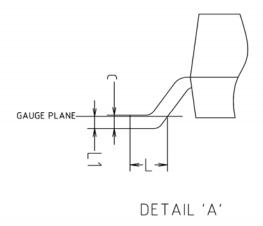


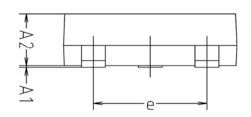
Ta=25°C f=1MHz, IE=0

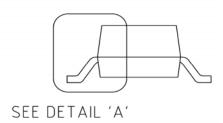
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Outline Dimension



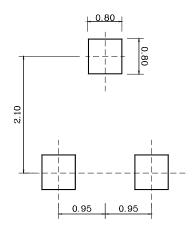






SYMBOL	MILLIMETERS			NOTE	
STIDOL	MINIMUM	NOMINAL	MAXIMUM	NOTE	
A1	0.00	-	0.10		
A2	0.82	-	1.02		
Ь	0.39	0.42	0.45		
С	0.09	0.12	0.15		
D	2.80	2.90	3.00		
Ε	2.20	2.40	2.60		
E1	1.20	1.30	1.40		
е	1.90BSC				
L	0.20	-	-		
L1	0.12BSC				

*Recommend PCB solder land [Unit: mm]



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